



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Fastow et al.

Serial No.: 10/658,936

Filed: September 9, 2003

For: FLASH MEMORY WITH
HIGH-K DIELECTRIC
MATERIAL BETWEEN
SUBSTRATE AND GATE

Examiner: NGUYEN, D.

Art Unit: 2818

Confirmation No.: 3102

Do Not Enter, Thanks!

dlh

11/07/05

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT AND RESPONSE
TO OFFICE ACTION

Dear Sir:

In response to the Office Action mailed August 18, 2005, please consider the following remarks and enter the following amendments. Amendments to the claims are presented beginning on page 2 of this response. Remarks begin on page 5.

AMD-H0561/JPH/WAZ
Examiner: NGUYEN, D.

1

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